What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	Coldfire V2
Core Size	32-Bit Single-Core
Speed	66MHz
Connectivity	I²C, SPI, UART/USART, USB OTG
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	43
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 8x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-VFQFN Exposed Pad
Supplier Device Package	64-QFN-EP (9x9)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mcf52210cep66

Table of Contents

    - Low-voltage detection (LVD)
    - JTAG
  - Status flag indication of source of last reset
- Chip configuration module (CCM)
  - System configuration during reset
  - Selects one of six clock modes
  - Configures output pad drive strength
  - Unique part identification number and part revision number
- General purpose I/O interface
  - Up to 56 bits of general purpose I/O
  - Bit manipulation supported via set/clear functions
  - Programmable drive strengths
  - Unused peripheral pins may be used as extra GPIO
- JTAG support for system level board testing

1.2.2 V2 Core Overview

The version 2 ColdFire processor core is comprised of two separate pipelines decoupled by an instruction buffer. The two-stage instruction fetch pipeline (IFP) is responsible for instruction-address generation and instruction fetch. The instruction buffer is a first-in-first-out (FIFO) buffer that holds prefetched instructions awaiting execution in the operand execution pipeline (OEP). The OEP includes two pipeline stages. The first stage decodes instructions and selects operands (DSOC); the second stage (AGEX) performs instruction execution and calculates operand effective addresses, if needed.

The V2 core implements the ColdFire instruction set architecture revision A+ with support for a separate user stack pointer register and four new instructions to assist in bit processing. Additionally, the core includes the multiply-accumulate (MAC) unit for improved signal processing capabilities. The MAC implements a three-stage arithmetic pipeline, optimized for 16x16 bit operations, with support for one 32-bit accumulator. Supported operands include 16- and 32-bit signed and unsigned integers, signed fractional operands, and a complete set of instructions to process these data types. The MAC provides support for execution of DSP operations within the context of a single processor at a minimal hardware cost.

1.2.3 Integrated Debug Module

The ColdFire processor core debug interface is provided to support system debugging with low-cost debug and emulator development tools. Through a standard debug interface, access to debug information and real-time tracing capability is provided on 100-lead packages. This allows the processor and system to be debugged at full speed without the need for costly in-circuit emulators.

The on-chip breakpoint resources include a total of nine programmable 32-bit registers: an address and an address mask register, a data and a data mask register, four PC registers, and one PC mask register. These registers can be accessed through the dedicated debug serial communication channel or from the processor's supervisor mode programming model. The breakpoint registers can be configured to generate triggers by combining the address, data, and PC conditions in a variety of single- or dual-level definitions. The trigger event can be programmed to generate a processor halt or initiate a debug interrupt exception. This device implements revision B+ of the ColdFire Debug Architecture.

The processor's interrupt servicing options during emulator mode allow real-time critical interrupt service routines to be serviced while processing a debug interrupt event. This ensures the system continues to operate even during debugging.

To support program trace, the V2 debug module provides processor status (PST[3:0]) and debug data (DDATA[3:0]) ports. These buses and the PSTCLK output provide execution status, captured operand data, and branch target addresses defining processor activity at the CPU's clock rate. The device includes a new debug signal, ALLPST. This signal is the logical AND of the processor status (PST[3:0]) signals and is useful for detecting when the processor is in a halted state (PST[3:0] = 1111).

The full debug/trace interface is available only on the 100-pin packages. However, every product features the dedicated debug serial communication channel (DSI, DSO, DSCLK) and the ALLPST signal.

1.2.4 JTAG

The processor supports circuit board test strategies based on the Test Technology Committee of IEEE and the Joint Test Action Group (JTAG). The test logic includes a test access port (TAP) consisting of a 16-state controller, an instruction register, and three test registers (a 1-bit bypass register, a 256-bit boundary-scan register, and a 32-bit ID register). The boundary scan register links the device's pins into one shift register. Test logic, implemented using static logic design, is independent of the device system logic.

The device implementation can:

- Perform boundary-scan operations to test circuit board electrical continuity
- Sample system pins during operation and transparently shift out the result in the boundary scan register
- Bypass the device for a given circuit board test by effectively reducing the boundary-scan register to a single bit
- Disable the output drive to pins during circuit-board testing
- Drive output pins to stable levels

1.2.5 On-Chip Memories

1.2.5.1 SRAM

The dual-ported SRAM module provides a general-purpose 8- or 16-Kbyte memory block that the ColdFire core can access in a single cycle. The location of the memory block can be set to any 8- or 16-Kbyte boundary within the 4-Gbyte address space. This memory is ideal for storing critical code or data structures and for use as the system stack. Because the SRAM module is physically connected to the processor's high-speed local bus, it can quickly service core-initiated accesses or memory-referencing commands from the debug module.

The SRAM module is also accessible by the DMA. The dual-ported nature of the SRAM makes it ideal for implementing applications with double-buffer schemes, where the processor and a DMA device operate in alternate regions of the SRAM to maximize system performance.

1.2.5.2 Flash Memory

The ColdFire flash module (CFM) is a non-volatile memory (NVM) module that connects to the processor's high-speed local bus. The CFM is constructed with up to four banks of 16-Kbyte×16-bit flash memory arrays to generate up to 128 Kbytes of 32-bit flash memory. These electrically erasable and programmable arrays serve as non-volatile program and data memory. The flash memory is ideal for program and data storage for single-chip applications, allowing for field reprogramming without requiring an external high voltage source. The CFM interfaces to the ColdFire core through an optimized read-only memory controller that supports interleaved accesses from the 2-cycle flash memory arrays. A backdoor mapping of the flash memory is used for all program, erase, and verify operations, as well as providing a read datapath for the DMA. Flash memory may also be programmed via the EzPort, which is a serial flash memory programming interface that allows the flash memory to be read, erased and programmed by an external controller in a format compatible with most SPI bus flash memory chips.

1.2.6 Power Management

The device incorporates several low-power modes of operation entered under program control and exited by several external trigger events. An integrated power-on reset (POR) circuit monitors the input supply and forces an MCU reset as the supply voltage rises. The low voltage detector (LVD) monitors the supply voltage and is configurable to force a reset or interrupt condition if it falls below the LVD trip point. The RAM standby switch provides power to RAM when the supply voltage to the chip falls below the standby battery voltage.

1.2.20 Interrupt Controller (INTC)

The device has a single interrupt controller that supports up to 63 interrupt sources. There are 56 programmable sources, 49 of which are assigned to unique peripheral interrupt requests. The remaining seven sources are unassigned and may be used for software interrupt requests.

1.2.21 DMA Controller

The direct memory access (DMA) controller provides an efficient way to move blocks of data with minimal processor intervention. It has four channels that allow byte, word, longword, or 16-byte burst line transfers. These transfers are triggered by software explicitly setting a DCR*n*[START] bit or by the occurrence of certain UART or DMA timer events.

1.2.22 Reset

The reset controller determines the source of reset, asserts the appropriate reset signals to the system, and keeps track of what caused the last reset. There are seven sources of reset:

- External reset input
- Power-on reset (POR)
- Watchdog timer
- Phase locked-loop (PLL) loss of lock / loss of clock
- Software
- Low-voltage detector (LVD)
- JTAG

Control of the LVD and its associated reset and interrupt are managed by the reset controller. Other registers provide status flags indicating the last source of reset and a control bit for software assertion of the $\overline{\text{RSTO}}$ pin.

1.2.23 GPIO

Nearly all pins on the device have general purpose I/O capability and are grouped into 8-bit ports. Some ports do not use all eight bits. Each port has registers that configure, monitor, and control the port pin.

1.2.24 Part Numbers and Packaging

This product is RoHS-compliant. Refer to the product page at freescale.com or contact your sales office for up-to-date RoHS information.

Table 2. Orderable Part Number Summary

Freescale Part Number	Description	Speed (MHz)	Flash/SRAM (Kbytes)	Package	Temp range (°C)
MCF52210CAE66	MCF52210 Microcontroller, 2 UARTs	66	64 / 16	64 LQFP	-40 to +85
MCF52210CEP66	MCF52210 Microcontroller, 2 UARTs	66	64 / 16	64 QFN	-40 to +85
MCF52210CVM66	MCF52210 Microcontroller, 2 UARTs	66	64 / 16	81 MAPBGA	-40 to +85
MCF52210CVM80	MCF52210 Microcontroller, 2 UARTs	80	64 / 16	81 MAPBGA	-40 to +85
MCF52211CAE66	MCF52211 Microcontroller, 2 UARTs	66	128 / 16	64 LQFP	-40 to +85
MCF52211CAF80	MCF52211 Microcontroller, 3 UARTs	80	128 / 16	100 LQFP	-40 to +85
MCF52211CEP66	MCF52211 Microcontroller, 2 UARTs	66	128 / 16	64 QFN	-40 to +85

Figure 3 shows the pinout configuration for the 81 MAPBGA.

	1	2	3	4	5	6	7	8	9
A	V_{SS}	UTXD1	$\overline{\text{RSTI}}$	$\overline{\text{IRQ5}}$	$\overline{\text{IRQ3}}$	ALLPST	TDO	TMS	V_{SS}
B	$\overline{\text{URTS1}}$	URXD1	$\overline{\text{RSTO}}$	$\overline{\text{IRQ6}}$	$\overline{\text{IRQ2}}$	$\overline{\text{TRST}}$	TDI	V_{DD}PLL	EXTAL
C	$\overline{\text{UCTS0}}$	TEST	$\overline{\text{UCTS1}}$	$\overline{\text{IRQ7}}$	$\overline{\text{IRQ4}}$	$\overline{\text{IRQ1}}$	TCLK	V_{SS}PLL	XTAL
D	URXD0	UTXD0	$\overline{\text{URTS0}}$	V_{SS}	V_{DD}	V_{SS}	PWM7	GPT3	GPT2
E	SCL	SDA	V_{DD}	V_{DD}	V_{DD}	V_{DD}	V_{DD}	PWM5	GPT1
F	QSPI_CS3	QSPI_CS2	QSPI_DIN	V_{SS}	V_{DD}	V_{SS}	GPT0	V_{STBY}	AN4
G	QSPI_DOUT	QSPI_CLK	$\overline{\text{RCON}}$	DTIN1	CLKMOD0	AN2	AN3	AN5	AN6
H	QSPI_CS0	QSPI_CS1	DTIN3	DTIN0	CLKMOD1	AN1	V_{SSA}	V_{DDA}	AN7
J	V_{SS}	JTAG_EN	DTIN2	PWM3	PWM1	AN0	V_{RL}	V_{RH}	V_{SSA}

Figure 3. 81 MAPBGA Pin Assignments

Table 3 shows the pin functions by primary and alternate purpose, and illustrates which packages contain each pin.

Table 3. Pin Functions by Primary and Alternate Purpose

Pin Group	Primary Function	Secondary Function	Tertiary Function	Quaternary Function	Drive Strength / Control[1]	Slew Rate / Control[1]	Pull-up / Pull-down[2]	Pin on 100 LQFP	Pin on 81 MAPBGA	Pin on 64 LQFP/QFN
ADC	AN7	—	—	GPIO	Low	FAST	—	51	H9	33
	AN6	—	—	GPIO	Low	FAST	—	52	G9	34
	AN5	—	—	GPIO	Low	FAST	—	53	G8	35
	AN4	—	—	GPIO	Low	FAST	—	54	F9	36
	AN3	—	—	GPIO	Low	FAST	—	46	G7	28
	AN2	—	—	GPIO	Low	FAST	—	45	G6	27
	AN1	—	—	GPIO	Low	FAST	—	44	H6	26
	AN0	—	—	GPIO	Low	FAST	—	43	J6	25
	SYNCA[3]	—	—	—	N/A	N/A	—	—	—	—
	SYNCB[3]	—	—	—	N/A	N/A	—	—	—	—
	VDDA	—	—	—	N/A	N/A	—	50	H8	32
	VSSA	—	—	—	N/A	N/A	—	47	H7, J9	29
	VRH	—	—	—	N/A	N/A	—	49	J8	31
	VRL	—	—	—	N/A	N/A	—	48	J7	30
Clock Generation	EXTAL	—	—	—	N/A	N/A	—	73	B9	47
	XTAL	—	—	—	N/A	N/A	—	72	C9	46
	VDDPLL	—	—	—	N/A	N/A	—	74	B8	48
	VSSPLL	—	—	—	N/A	N/A	—	71	C8	45
Debug Data	ALLPST	—	—	—	High	FAST	—	86	A6	55
	DDATA[3:0]	—	—	GPIO	High	FAST	—	84,83,78,77	—	—
	PST[3:0]	—	—	GPIO	High	FAST	—	70,69,66,65	—	—
I^2C	SCL	USB_DMI	UTXD2	GPIO	PDSR[0]	PSRR[0]	pull-up[4]	10	E1	8
	SDA	USB_DPI	URXD2	GPIO	PDSR[0]	PSRR[0]	pull-up[4]	11	E2	9

Table 3. Pin Functions by Primary and Alternate Purpose (continued)

Pin Group	Primary Function	Secondary Function	Tertiary Function	Quaternary Function	Drive Strength / Control[1]	Slew Rate / Control[1]	Pull-up / Pull-down[2]	Pin on 100 LQFP	Pin on 81 MAPBGA	Pin on 64 LQFP/QFN
Interrupts	$\overline{\text{IRQ7}}$	—	—	GPIO	Low	FAST	—	95	C4	58
	$\overline{\text{IRQ6}}$	—	—	GPIO	Low	FAST	—	94	B4	—
	$\overline{\text{IRQ5}}$	—	—	GPIO	Low	FAST	—	91	A4	—
	$\overline{\text{IRQ4}}$	—	—	GPIO	Low	FAST	—	90	C5	57
	$\overline{\text{IRQ3}}$	—	—	GPIO	Low	FAST	—	89	A5	—
	$\overline{\text{IRQ2}}$	—	—	GPIO	Low	FAST	—	88	B5	—
	$\overline{\text{IRQ1}}$	SYNCA	USB_ALT_CLK	GPIO	High	FAST	pull-up[4]	87	C6	56
JTAG/BDM	JTAG_EN	—	—	—	N/A	N/A	pull-down	26	J2	17
	TCLK/ PSTCLK	CLKOUT	—	—	High	FAST	pull-up[5]	64	C7	44
	TDI/DSI	—	—	—	N/A	N/A	pull-up[5]	79	B7	50
	TDO/DSO	—	—	—	High	FAST	—	80	A7	51
	TMS /$\overline{\text{BKPT}}$	—	—	—	N/A	N/A	pull-up[5]	76	A8	49
	$\overline{\text{TRST}}$ /DSCLK	—	—	—	N/A	N/A	pull-up[5]	85	B6	54
Mode Selection[6]	CLKMOD0	—	—	—	N/A	N/A	pull-down[6]	40	G5	24
	CLKMOD1	—	—	—	N/A	N/A	pull-down[6]	39	H5	—
	$\overline{\text{RCON}}$/ EZPCS	—	—	—	N/A	N/A	pull-up	21	G3	16

Table 7. Clocking Modes (continued)

CLKMOD[1:0]	XTAL	Configure the clock mode.
01	N/A	PLL disabled, clock driven by crystal
10	0	PLL in normal mode, clock driven by external oscillator[1]
10	1	Reserved[2]
11	N/A	PLL in normal mode, clock driven by crystal

[1] The PLL pre-divider (CCHR+1) reset value is 6 and the PLL input reference range is 2–10 MHz, so in order to boot with the PLL enabled, the external clock or crystal frequency needs to be greater than 12 MHz. MCF5221x devices cannot boot with PLL enabled from an external clock or crystal oscillator with frequency less than 12 MHz. This constraint does not apply to booting with PLL disabled.

[2] Cannot boot from the Internal 8 MHz Relaxation oscillator with the PLL enabled. Refer Note1. Thus this mode has been removed from the table.

1.6 External Interrupt Signals

Table 8 describes the external interrupt signals.

Table 8. External Interrupt Signals

Signal Name	Abbreviation	Function	I/O
External Interrupts	$\overline{\text{IRQ}}$[7:1]	External interrupt sources.	I

1.7 Queued Serial Peripheral Interface (QSPI)

Table 9 describes the QSPI signals.

Table 9. Queued Serial Peripheral Interface (QSPI) Signals

Signal Name	Abbreviation	Function	I/O
QSPI Synchronous Serial Output	QSPI_DOUT	Provides the serial data from the QSPI and can be programmed to be driven on the rising or falling edge of QSPI_CLK.	O
QSPI Synchronous Serial Data Input	QSPI_DIN	Provides the serial data to the QSPI and can be programmed to be sampled on the rising or falling edge of QSPI_CLK.	I
QSPI Serial Clock	QSPI_CLK	Provides the serial clock from the QSPI. The polarity and phase of QSPI_CLK are programmable.	O
Synchronous Peripheral Chip Selects	QSPI_CS[3:0]	QSPI peripheral chip select; can be programmed to be active high or low.	O

1.8 USB On-the-Go

This device is compliant with industry standard USB 2.0 specification.

1.9 I^{2}C I/O Signals

Table 10 describes the I^{2}C serial interface module signals.

Table 10. I^2C I/O Signals

Signal Name	Abbreviation	Function	I/O
Serial Clock	SCLn	Open-drain clock signal for the for the I^2C interface. When the bus is In master mode, this clock is driven by the I^2C module; when the bus is in slave mode, this clock becomes the clock input.	I/O
Serial Data	SDAn	Open-drain signal that serves as the data input/output for the I^2C interface.	I/O

1.10 UART Module Signals

Table 11 describes the UART module signals.

Table 11. UART Module Signals

Signal Name	Abbreviation	Function	I/O
Transmit Serial Data Output	UTXD*n*	Transmitter serial data outputs for the UART modules. The output is held high (mark condition) when the transmitter is disabled, idle, or in the local loopback mode. Data is shifted out, LSB first, on this pin at the falling edge of the serial clock source.	O
Receive Serial Data Input	URXD*n*	Receiver serial data inputs for the UART modules. Data is received on this pin LSB first. When the UART clock is stopped for power-down mode, any transition on this pin restarts the clock.	I
Clear-to-Send	$\overline{\text{UCTS}}$*n*	Indication to the UART modules that they can begin data transmission.	I
Request-to-Send	$\overline{\text{URTS}}$*n*	Automatic request-to-send outputs from the UART modules. This signal can also be configured to be asserted and negated as a function of the RxFIFO level.	O

1.11 DMA Timer Signals

Table 12 describes the signals of the four DMA timer modules.

Table 12. DMA Timer Signals

Signal Name	Abbreviation	Function	I/O
DMA Timer Input	DTIN	Event input to the DMA timer modules.	I
DMA Timer Output	DTOUT	Programmable output from the DMA timer modules.	O

Table 27. DC Electrical Specifications (continued)[1]

Characteristic	Symbol	Min	Max	Unit
Output high voltage (high drive) I_{OH} = -5 mA	V_{OH}	V_{DD} – 0.5	—	V
Output low voltage (high drive) I_{OL} = 5 mA	V_{OL}	—	0.5	V
Output high voltage (low drive) I_{OH} = -2 mA	V_{OH}	V_{DD} - 0.5	—	V
Output low voltage (low drive) I_{OL} = 2 mA	V_{OL}	—	0.5	V
Weak internal pull Up device current, tested at V_{IL} Max.[3]	I_{APU}	–10	–130	µA
Input Capacitance [4] • All input-only pins • All input/output (three-state) pins	C_{in}	 — —	 7 7	pF

[1] Refer to Table 28 for additional PLL specifications.

[2] Only for pins: IRQ1, IRQ2. IRQ3, IRQ4, IRQ5, IRQ6. IRQ7, RSTIN_B, RCON_B, PCS0, SCK, I2C_SDA, I2C_SCL, TCLK, TRST_B, TEST

[3] Refer toTable 3 for pins having internal pull-up devices.

[4] This parameter is characterized before qualification rather than 100% tested.

2.8 Clock Source Electrical Specifications

Table 28. Oscillator and PLL Electrical Specifications

(V_{DD} and V_{DDPLL} = 2.7 to 3.6 V, V_{SS} = V_{SSPLL} = 0 V)

Characteristic	Symbol	Min	Max	Unit
Clock Source Frequency Range of EXTAL Frequency Range • Crystal • External[1]	 $f_{crystal}$ f_{ext}	 1 0	 25.0[2] 50-80	MHz
PLL reference frequency range	f_{ref_pll}	2	10.0	MHz
System frequency [3] • External clock mode • On-chip PLL frequency	f_{sys}	 0 f_{ref} / 32	 50-80[4] 50-80[4]	MHz
Loss of reference frequency [5, 7]	f_{LOR}	100	1000	kHz
Self clocked mode frequency [6]	f_{SCM}	1	5	MHz
Crystal start-up time [7, 8]	t_{cst}	—	0.1	ms
EXTAL input high voltage • External reference	V_{IHEXT}	 2.0	 3.0[2]	V
EXTAL input low voltage • External reference	V_{ILEXT}	 V_{SS}	 0.8	V
PLL lock time[4,9]	t_{lpll}	—	500	µs
Duty cycle of reference [4]	t_{dc}	40	60	% f_{ref}

Table 28. Oscillator and PLL Electrical Specifications (continued)

(V_{DD} and V_{DDPLL} = 2.7 to 3.6 V, V_{SS} = V_{SSPLL} = 0 V)

Characteristic	Symbol	Min	Max	Unit
Frequency un-LOCK range	f_{UL}	–1.5	1.5	% f_{ref}
Frequency LOCK range	f_{LCK}	–0.75	0.75	% f_{ref}
CLKOUT period jitter [4, 5, 10 ,11], measured at f_{SYS} Max • Peak-to-peak (clock edge to clock edge) • Long term (averaged over 2 ms interval)	C_{jitter}	 — —	 10 .01	% f_{sys}
On-chip oscillator frequency	f_{oco}	7.84	8.16	MHz

[1] In external clock mode, it is possible to run the chip directly from an external clock source without enabling the PLL.

[2] This value has been updated.

[3] All internal registers retain data at 0 Hz.

[4] Depending on packaging; see the orderable part number summary.

[5] Loss of Reference Frequency is the reference frequency detected internally, which transitions the PLL into self clocked mode.

[6] Self clocked mode frequency is the frequency at which the PLL operates when the reference frequency falls below f_{LOR} with default MFD/RFD settings.

[7] This parameter is characterized before qualification rather than 100% tested.

[8] Proper PC board layout procedures must be followed to achieve specifications.

[9] This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR).

[10] Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{sys}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{jitter} percentage for a given interval.

[11] Based on slow system clock of 40 MHz measured at f_{sys} max.

2.9 USB Operation

Table 29. USB Operation Specifications

Characteristic	Symbol	Value	Unit
Minimum core speed for USB operation	$f_{sys\_USB\_min}$	16	MHz

2.10 General Purpose I/O Timing

GPIO can be configured for certain pins of the QSPI, DDR Control, timer, UART, Interrupt and USB interfaces. When in GPIO mode, the timing specification for these pins is given in Table 30 and Figure 5.

The GPIO timing is met under the following load test conditions:

- 50 pF / 50 Ω for high drive
- 25 pF / 25 Ω for low drive

Figure 7 shows timing for the values in Table 32 and Table 33.

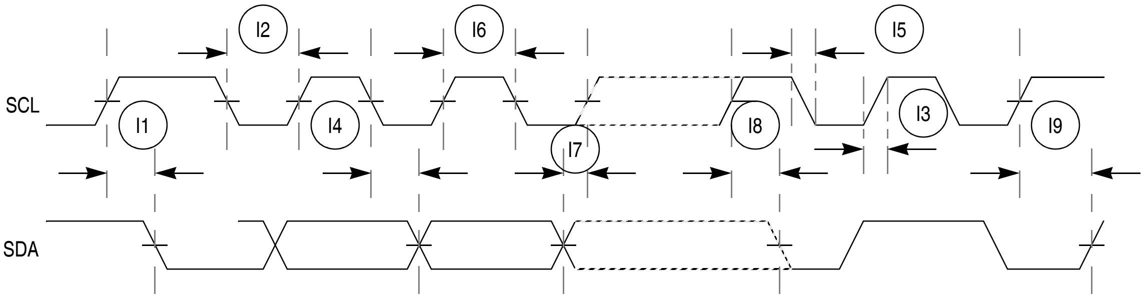


Figure 7. I^2C Input/Output Timings

2.13 Analog-to-Digital Converter (ADC) Parameters

Table 34 lists specifications for the analog-to-digital converter.

Table 34. ADC Parameters[1]

Name	Characteristic	Min	Typical	Max	Unit
V_{REFL}	Low reference voltage	V_{SS}	—	V_{REFH}	V
V_{REFH}	High reference voltage	V_{REFL}	—	V_{DDA}	V
V_{DDA}	ADC analog supply voltage	3.0	3.3	3.6	V
V_{ADIN}	Input voltages	V_{REFL}	—	V_{REFH}	V
RES	Resolution	12	—	12	Bits
INL	Integral non-linearity (full input signal range)[2]	—	±2.5	±3	LSB[3]
INL	Integral non-linearity (10% to 90% input signal range)[4]	—	±2.5	±3	LSB
DNL	Differential non-linearity	—	$-1 < DNL < +1$	$<+1$	LSB
Monotonicity		GUARANTEED			
f_{ADIC}	ADC internal clock	0.1	—	5.0	MHz
R_{AD}	Conversion range	V_{REFL}	—	V_{REFH}	V
t_{ADPU}	ADC power-up time[5]	—	6	13	t_{AIC} cycles[6]
t_{REC}	Recovery from auto standby	—	0	1	t_{AIC} cycles
t_{ADC}	Conversion time	—	6	—	t_{AIC} cycles
t_{ADS}	Sample time	—	1	—	t_{AIC} cycles
C_{ADI}	Input capacitance	—	See Figure 8	—	pF
X_{IN}	Input impedance	—	See Figure 8	—	W
I_{ADI}	Input injection current[7], per pin	—	—	3	mA
I_{VREFH}	V_{REFH} current	—	0	—	mA
V_{OFFSET}	Offset voltage internal reference	—	±8	±15	mV
E_{GAIN}	Gain error (transfer path)	.99	1	1.01	—
V_{OFFSET}	Offset voltage external reference	—	±3	9	mV
SNR	Signal-to-noise ratio	—	62 to 66	—	dB

Table 34. ADC Parameters[1] (continued)

Name	Characteristic	Min	Typical	Max	Unit
THD	Total harmonic distortion	—	–75	—	dB
SFDR	Spurious free dynamic range	—	67 to 70.3	—	dB
SINAD	Signal-to-noise plus distortion	—	61 to 63.9	—	dB
ENOB	Effective number of bits	9.1	10.6	—	Bits

[1] All measurements are preliminary pending full characterization, and made at V_{DD} = 3.3V, V_{REFH} = 3.3V, and V_{REFL} = ground

[2] INL measured from $V_{IN} = V_{REFL}$ to $V_{IN} = V_{REFH}$

[3] LSB = Least Significant Bit

[4] INL measured from $V_{IN} = 0.1V_{REFH}$ to $V_{IN} = 0.9V_{REFH}$

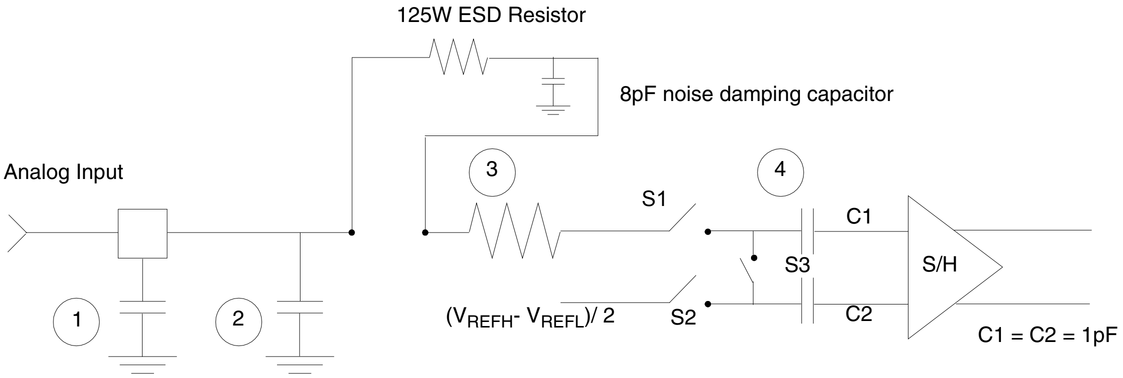
[5] Includes power-up of ADC and V_{REF}

[6] ADC clock cycles

[7] Current that can be injected or sourced from an unselected ADC signal input without impacting the performance of the ADC

2.14 Equivalent Circuit for ADC Inputs

Figure 8 shows the ADC input circuit during sample and hold. S1 and S2 are always open/closed at the same time that S3 is closed/open. When S1/S2 are closed & S3 is open, one input of the sample and hold circuit moves to (V_{REFH}-V_{REFL})/2, while the other charges to the analog input voltage. When the switches are flipped, the charge on C1 and C2 are averaged via S3, with the result that a single-ended analog input is switched to a differential voltage centered about (V_{REFH}-V_{REFL})/2. The switches switch on every cycle of the ADC clock (open one-half ADC clock, closed one-half ADC clock). There are additional capacitances associated with the analog input pad, routing, etc., but these do not filter into the S/H output voltage, as S1 provides isolation during the charge-sharing phase. One aspect of this circuit is that there is an on-going input current, which is a function of the analog input voltage, V_{REF} and the ADC clock frequency.



1. Parasitic capacitance due to package, pin-to-pin and pin-to-package base coupling; 1.8pF
2. Parasitic capacitance due to the chip bond pad, ESD protection devices and signal routing; 2.04pF
3. Equivalent resistance for the channel select mux; 100 Ωs
4. Sampling capacitor at the sample and hold circuit. Capacitor C1 is normally disconnected from the input and is only connected to it at sampling time; 1.4pF
5. Equivalent input impedance, when the input is selected = $\frac{1}{(\text{ADC Clock Rate}) \times (1.4\times10^{-12})}$

Figure 8. Equivalent Circuit for A/D Loading

Table 37. JTAG and Boundary Scan Timing

Num	Characteristics[1]	Symbol	Min	Max	Unit
J1	TCLK frequency of operation	f_{JCYC}	DC	1/4	$f_{sys/2}$
J2	TCLK cycle period	t_{JCYC}	$4 \times t_{CYC}$	—	ns
J3	TCLK clock pulse width	t_{JCW}	26	—	ns
J4	TCLK rise and fall times	t_{JCRF}	0	3	ns
J5	Boundary scan input data setup time to TCLK rise	t_{BSDST}	4	—	ns
J6	Boundary scan input data hold time after TCLK rise	t_{BSDHT}	26	—	ns
J7	TCLK low to boundary scan output data valid	t_{BSDV}	0	33	ns
J8	TCLK low to boundary scan output high Z	t_{BSDZ}	0	33	ns
J9	TMS, TDI input data setup time to TCLK rise	t_{TAPBST}	4	—	ns
J10	TMS, TDI Input data hold time after TCLK rise	t_{TAPBHT}	10	—	ns
J11	TCLK low to TDO data valid	t_{TDODV}	0	26	ns
J12	TCLK low to TDO high Z	t_{TDODZ}	0	8	ns
J13	$\overline{\text{TRST}}$ assert time	t_{TRSTAT}	100	—	ns
J14	$\overline{\text{TRST}}$ setup time (negation) to TCLK high	t_{TRSTST}	10	—	ns

[1] JTAG_EN is expected to be a static signal. Hence, it is not associated with any timing.

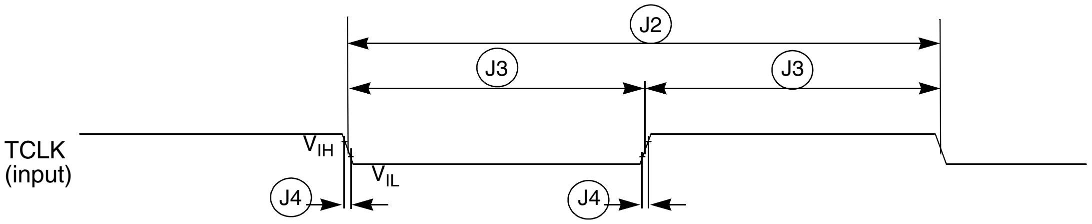


Figure 10. Test Clock Input Timing

Figure 15 shows BDM serial port AC timing for the values in Table 38.

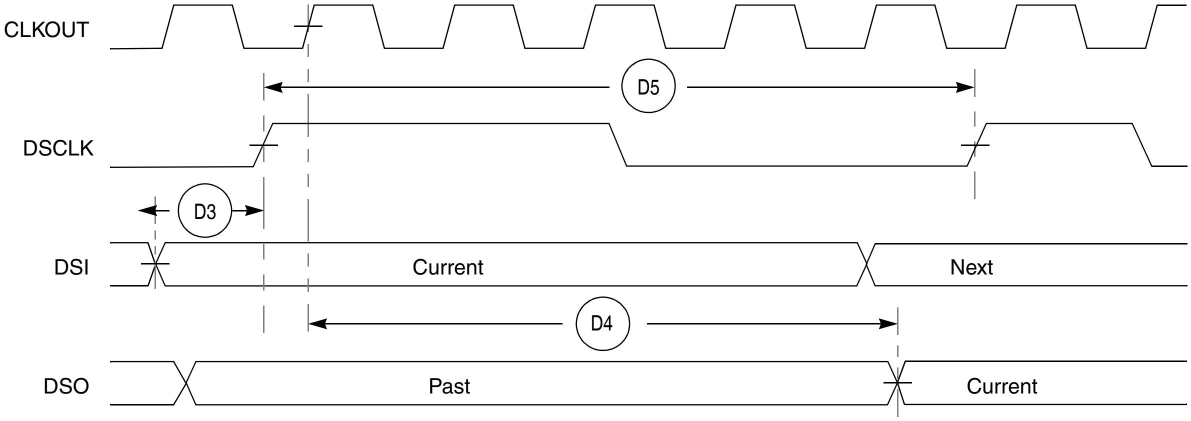
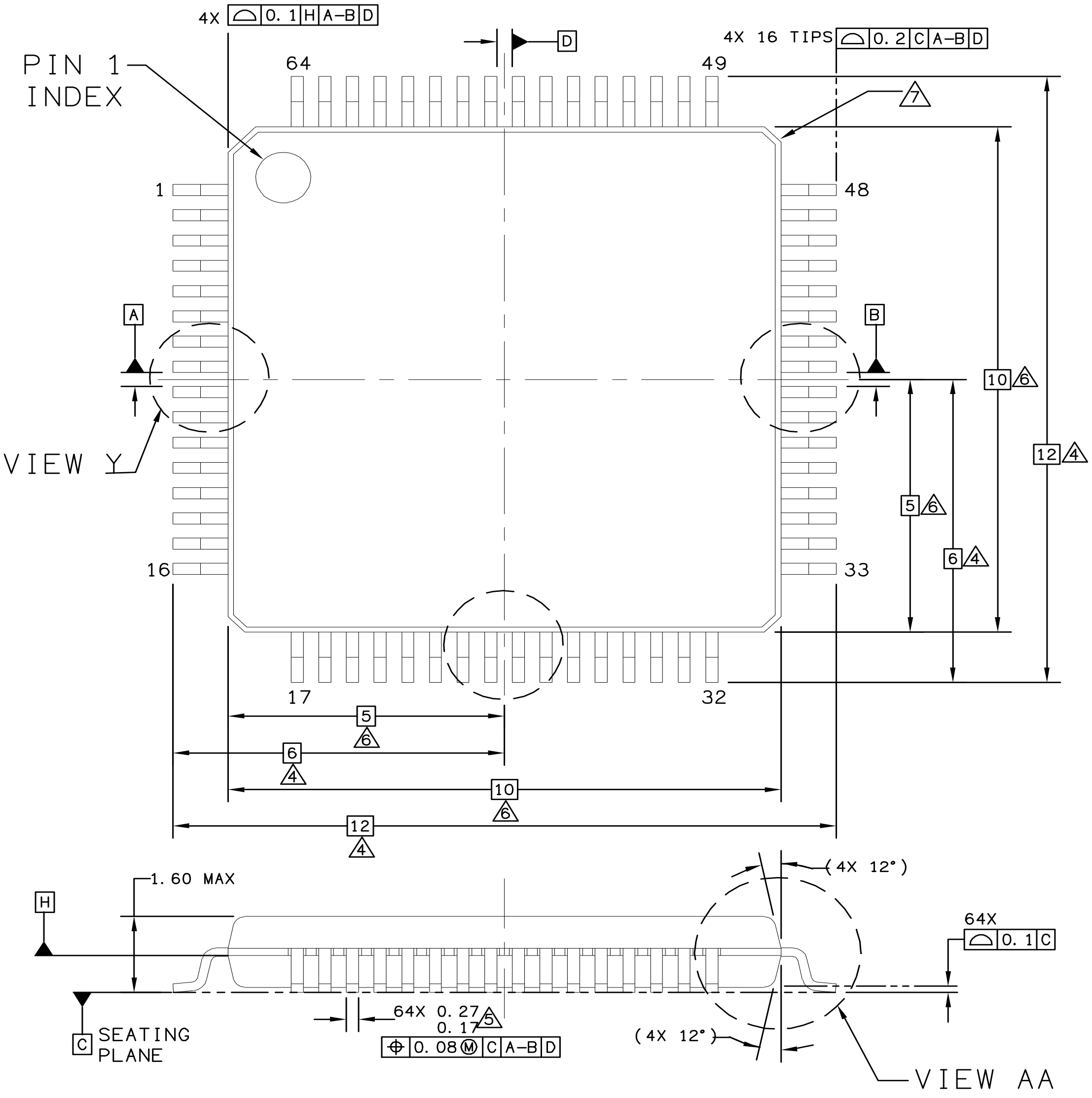


Figure 15. BDM Serial Port AC Timing

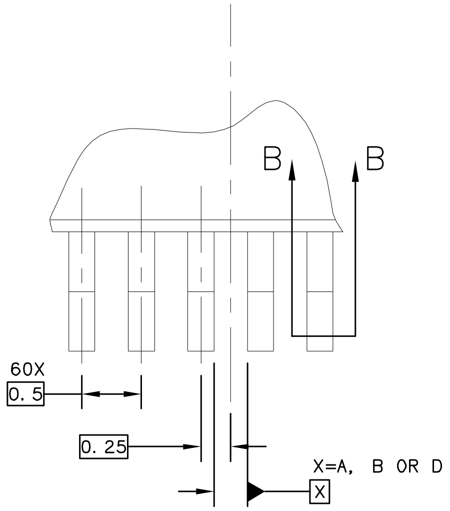
3 Mechanical Outline Drawings

This section describes the physical properties of the device and its derivatives.

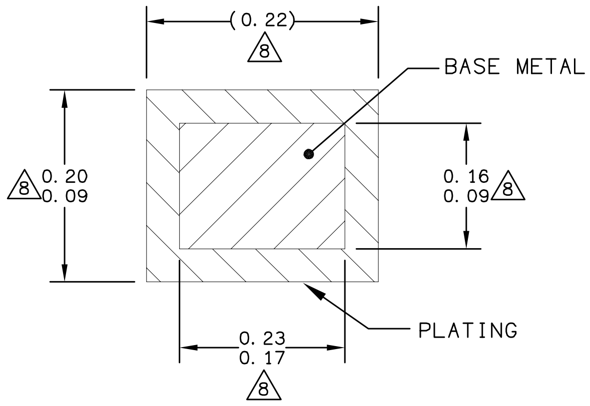
3.1 64-pin LQFP Package



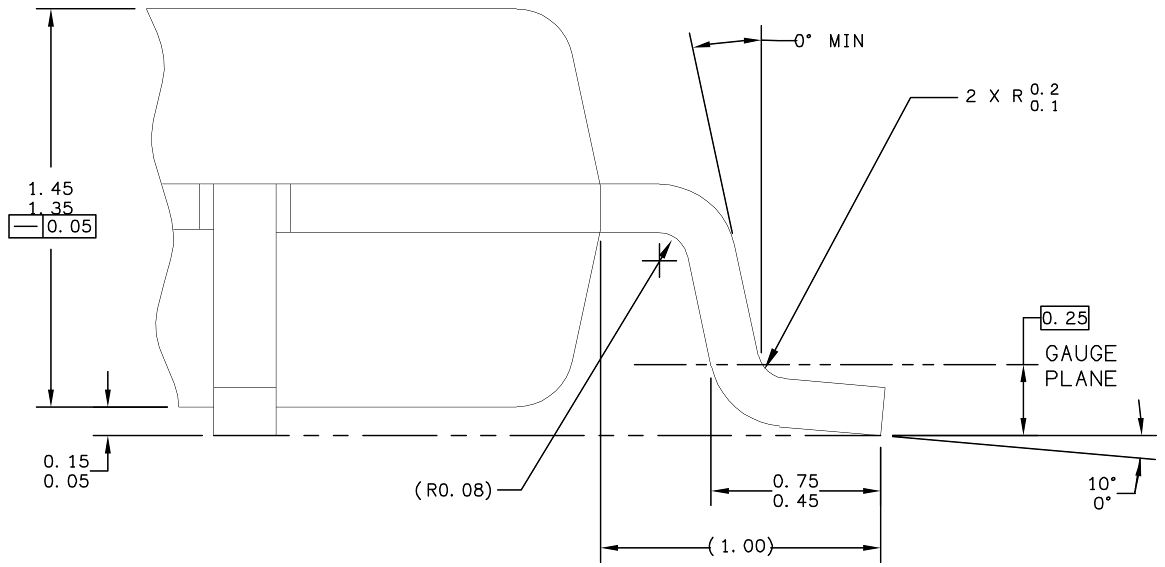
© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE
TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE	DOCUMENT NO: 98ASS23234W	REV: D
	CASE NUMBER: 840F-02	06 APR 2005
	STANDARD: JEDEC MS-026 BCD	



VIEW Y



SECTION B–B

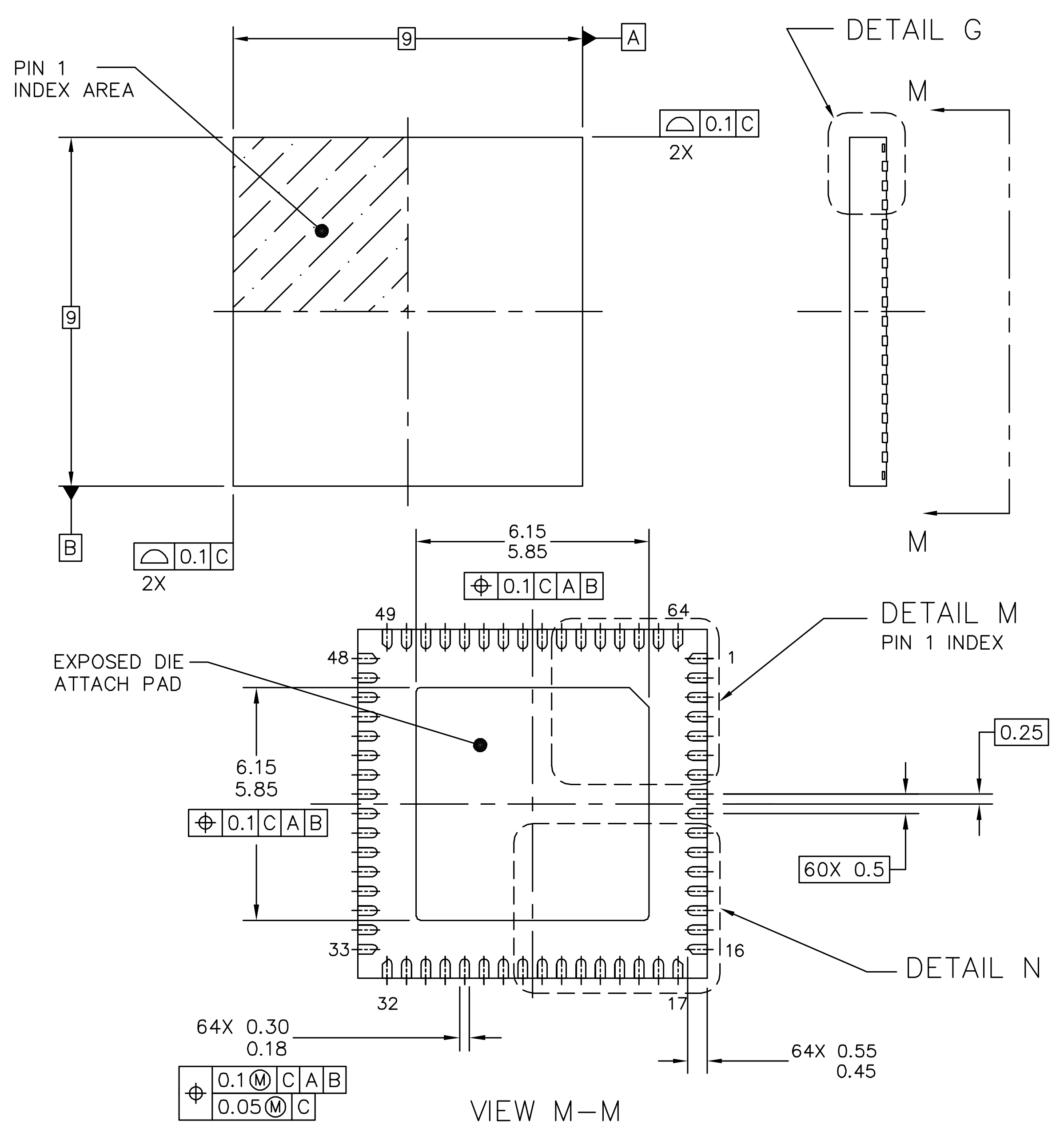


VIEW AA

© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE
TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE	DOCUMENT NO: 98ASS23234W	REV: D
	CASE NUMBER: 840F–02	06 APR 2005
	STANDARD: JEDEC MS–026 BCD	

3.2 64 QFN Package

	MECHANICAL OUTLINES DICTIONARY	DOCUMENT NO: 98ASA10690D
		PAGE: 1740
	DO NOT SCALE THIS DRAWING	REV: 0



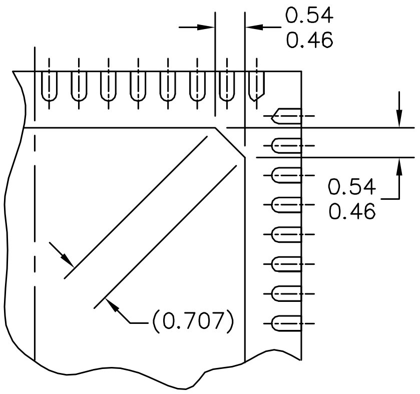
TITLE: THERMALLY ENHANCED QUAD FLAT NON–LEADED PACKAGE (QFN) 64 TERMINAL, 0.5 PITCH (9 X 9 X 1)	CASE NUMBER: 1740–01	
	STANDARD: JEDEC MO–220 VMMD–3	
	PACKAGE CODE: 6200	SHEET: 1 OF 4

freescale semiconductor

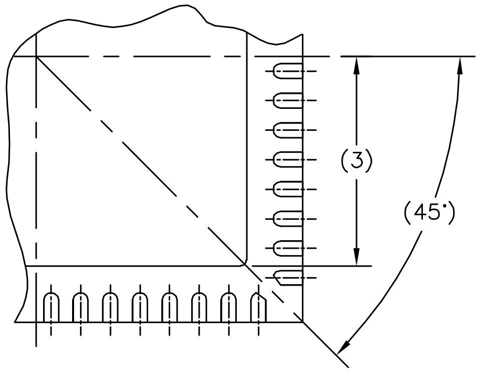
MECHANICAL OUTLINES DICTIONARY

DO NOT SCALE THIS DRAWING

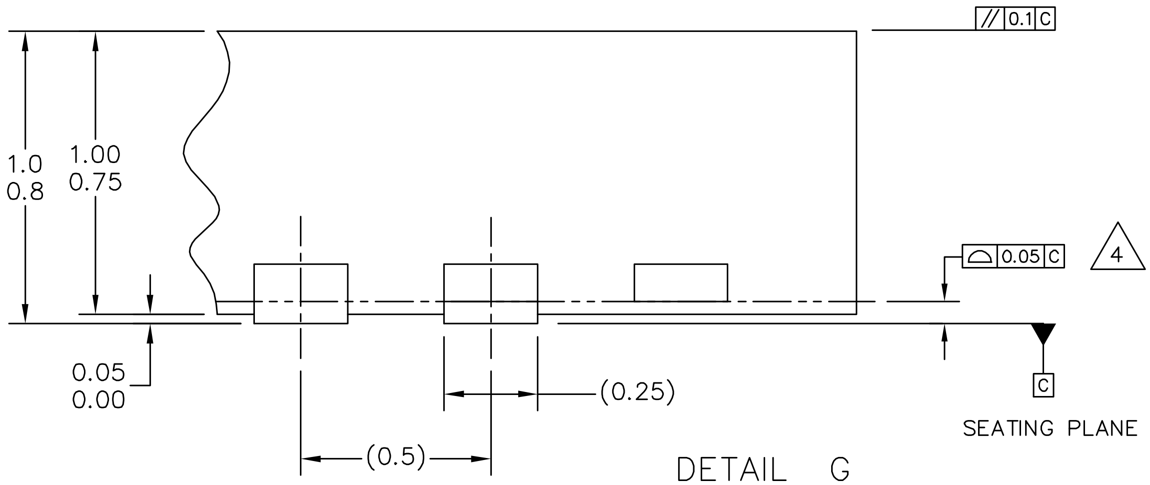
DOCUMENT NO: 98ASA10690D
PAGE: 1740
REV: O



DETAIL M
PREFERRED PIN1 BACKSIDE IDENTIFIER



DETAIL N
PREFERRED CORNER CONFIGURATION

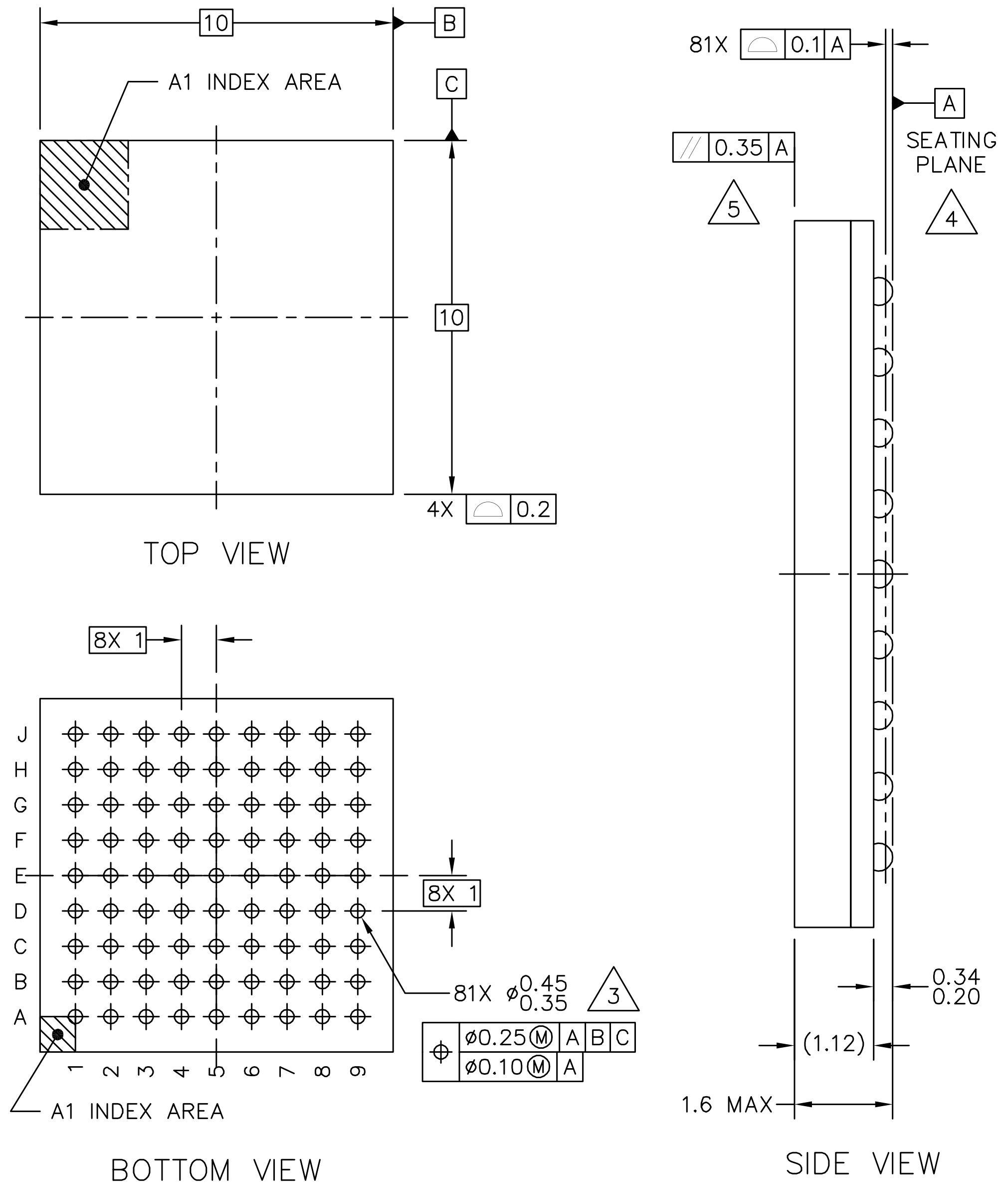


DETAIL G
VIEW ROTATED 90° CW

TITLE: THERMALLY ENHANCED QUAD
FLAT NON-LEADED PACKAGE (QFN)
64 TERMINAL, 0.5 PITCH (9 X 9 X 1)

CASE NUMBER: 1740-01
STANDARD: JEDEC MO-220 VMMD-3
PACKAGE CODE: 6200
SHEET: 2 OF 4

3.3 81 MAPBGA Package



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	**MECHANICAL OUTLINE**	PRINT VERSION NOT TO SCALE	
TITLE: PBGA, LOW PROFILE, 81 I/O, 10 X 10 PKG, 1 MM PITCH (MAP)	DOCUMENT NO: 98ASA10670D		REV: 0
	CASE NUMBER: 1662–01		04 FEB 2005
	STANDARD: NON–JEDEC		